



## Silicon Carbide Schottky Diode

## Features

- Positive temperature coefficient
- Temperature-independent switching
- Maximum working temperature at 175 °C
- Unipolar devices and zero reverse recovery current
- Zero forward recovery current
- Essentially no switching losses
- Reduction of heat sink requirements
- AEC-Q101 qualified
- High-frequency operation
- Reduction of EMI

## Typical Applications

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

## Mechanical Data

• **Package:** TO-247AB

Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant, halogen-free

• **Terminals:** Tin plated leads

• **Polarity:** As marked

Maximum Ratings (T<sub>C</sub>=25 °C Unless otherwise specified)

| PARAMETER                                                   | SYMBOL           | UNIT | VALUE         |
|-------------------------------------------------------------|------------------|------|---------------|
| Device marking code                                         |                  |      | D112040NCTQG3 |
| Reverse voltage (Repetitive peak)<br>@ T <sub>J</sub> =25°C | V <sub>RRM</sub> | V    | 1200          |
| Reverse voltage (Surge peak)<br>@ T <sub>J</sub> =25°C      | V <sub>RSM</sub> | V    | 1200          |
| Reverse voltage (DC)<br>@ T <sub>J</sub> =25°C              | V <sub>DC</sub>  | V    | 1200          |
| Continuous forward current @ T <sub>C</sub> =25°C           | I <sub>F</sub>   | A    | 43/86         |
| Continuous forward current @ T <sub>C</sub> =135°C          |                  |      | 20/40 =170/41 |

|                                                       |                                  |                  |                    |
|-------------------------------------------------------|----------------------------------|------------------|--------------------|
|                                                       |                                  |                  |                    |
| i <sup>2</sup> t Value@ T <sub>C</sub> =25°C ,tp=10ms | ∫ i <sup>2</sup> dt              | A <sup>2</sup> S | 128 <sup>(1)</sup> |
| Operating junction and Storage temperature range      | T <sub>J</sub> ,T <sub>stg</sub> | °C               | -55 to +175        |

(1) Per Leg, (2)



## Electrical Characteristics (Per Leg)

| PARAMETER                 | SYMBOL | UNIT    | TEST CONDITIONS                                      | Typ. | Max. |
|---------------------------|--------|---------|------------------------------------------------------|------|------|
| Forward voltage drop      | $V_F$  | V       | $I_F=20A, T_J=25^{\circ}C$                           | 1.45 | 1.55 |
|                           |        |         | $I_F=20A, T_J=175^{\circ}C$                          | 2.1  | -    |
| Reverse leakage current   | $I_R$  | $\mu A$ | $V_R=1200V, T_J=25^{\circ}C$                         | 3    | 20   |
|                           |        |         | $V_R=1200V, T_J=175^{\circ}C$                        | 19   | -    |
| Total capacitive charge   | $Q_C$  | nC      | $V_R=800V, T_J=25^{\circ}C, Q_C=\int_0^{V_R} C(V)dV$ | 91   | -    |
| Total capacitance         | C      | pF      | $V_R=0V, f=1MHz$                                     | 1280 | -    |
|                           |        |         | $V_R=400V, f=1MHz$                                   | 87   | -    |
|                           |        |         | $V_R=800V, f=1MHz$                                   | 64   | -    |
| Capacitance Stored Energy | $E_C$  | $\mu J$ | $V_R=800V$                                           | 23   | -    |

## Thermal Characteristics (Ta=25 Unless otherwise specified)

| PARAMETER          | SYMBOL      | UNIT          | VALUE                                      |
|--------------------|-------------|---------------|--------------------------------------------|
| Thermal resistance | $R_{d-j-c}$ | $^{\circ}C/W$ | 0.91 <sup>(1)</sup><br>0.46 <sup>(2)</sup> |

<sup>(1)</sup> Per Leg, <sup>(2)</sup> Per Device

## Typical Characteristics (Per Leg)

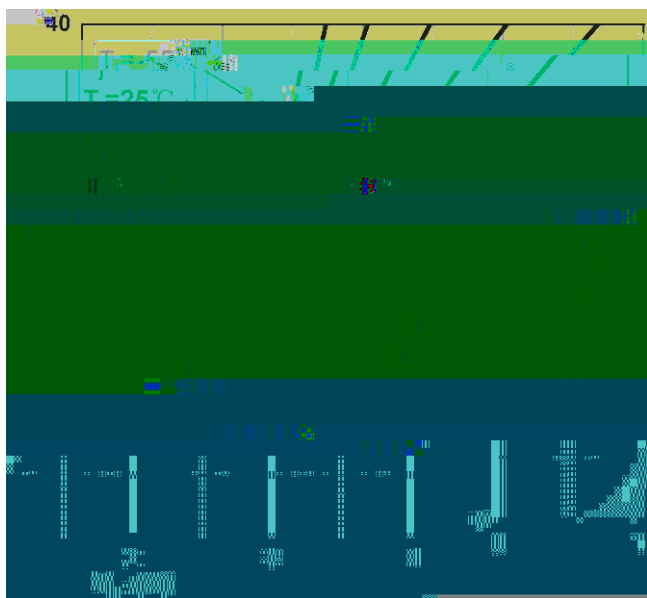


Figure 1. Forward Characteristics

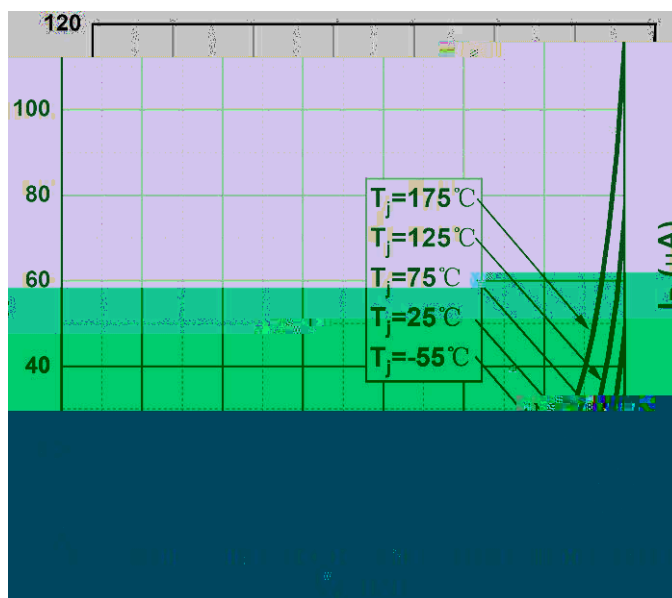


Figure 2. Reverse Characteristics

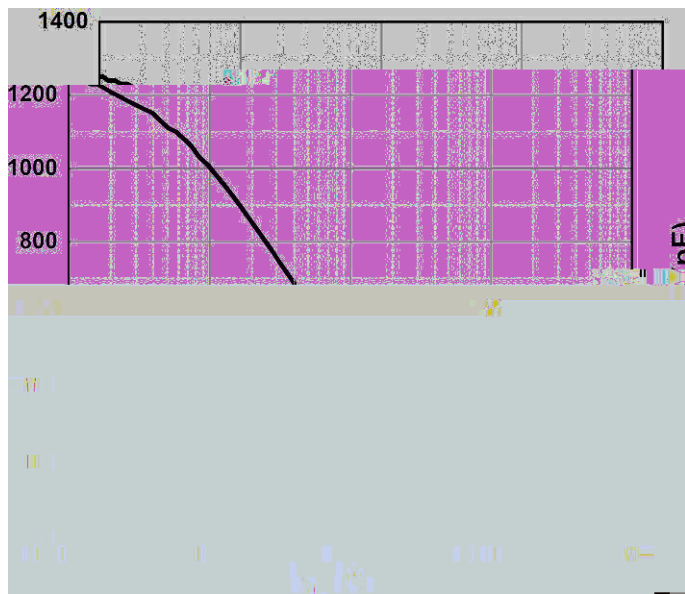


Figure 3. Capacitance vs. Reverse Voltage

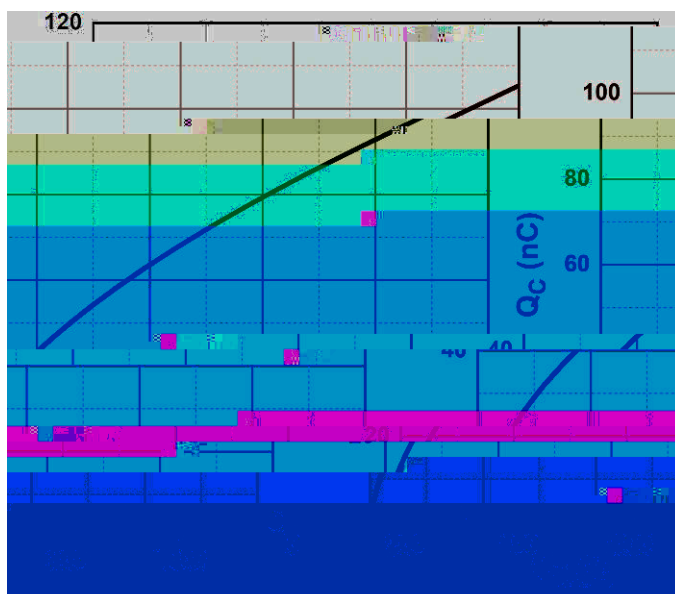


Figure 4. Total Capacitance Charge vs. Reverse Voltage

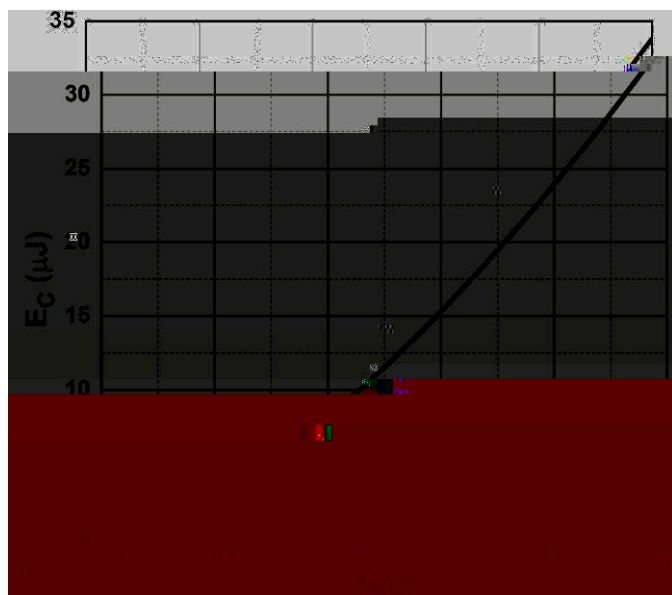


Figure 5. Capacitance Stored Energy

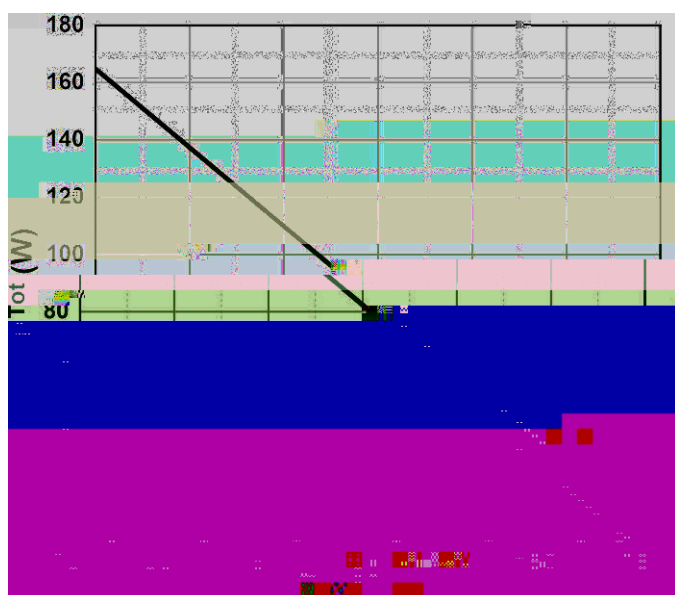


Figure 6. Power Derating

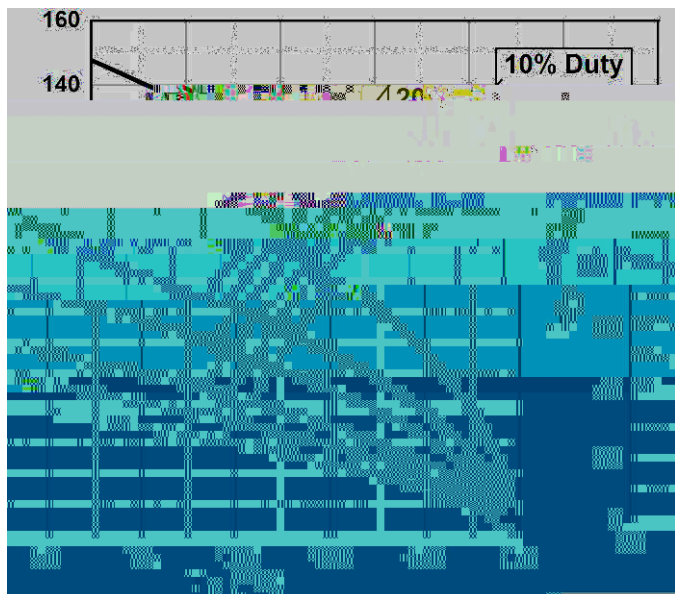


Figure 7. Current Derating

## Typical Characteristics (Device)

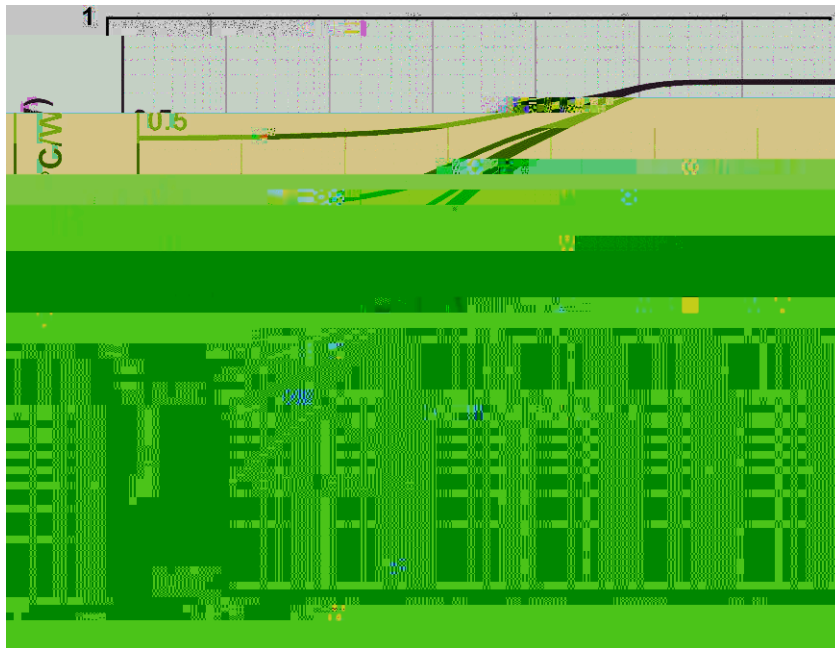


Figure 8. Transient Thermal Impedance



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